



100V PNP MEDIUM POWER TRANSISTOR IN SOT23

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirement of Automotive Applications.

Features

- BV_{CEO} > -100V
- Maximum Continuous Collector Current I_C = -1A
- V_{CE(SAT)} < -220mV @ -1A
- R_{CE(SAT)} = 150mΩ
- 7V Reverse Blocking Voltage
- High Peak Current
- Complementary Part Number ZXTN25100CFH
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.008 grams (Approximate)

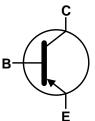
Applications

- MOSFET and IGBT Gate Driving
- DC DC Converters
- Motor Drive
- High Side Driver

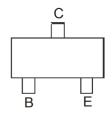
SOT23







Device Symbol



Top View Pin-Out

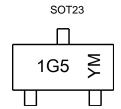
Ordering Information (Note 5)

ĺ	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	ZXTP25100CFHQTA	Automotive	1G5	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



1G5 = Product Type Marking Code YM = Date Code Marking Y = Year ex: F = 2018 M = Month ex: 9 = September

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	F	G	Н	!	J	K	L	М	N	0	Р	Q
Month	lan	Feb	Mar	Anr	May	lum	Jul	Aug	Sep	Oct	Nov	Dec
WOITH	Jan	reb	Iviar	Apr	iviay	Jun	Jui	Aug	ОСР	OCL	INOV	Dec

ZXTP25100CFHQ
Document number: DS41475 Rev. 2 - 2



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-115	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Collector voltage (Reverse Blocking)	V _{ECO}	-7	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-1	А
Base Current	I _B	-500	mA
Peak Pulse Current	Icm	-3	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

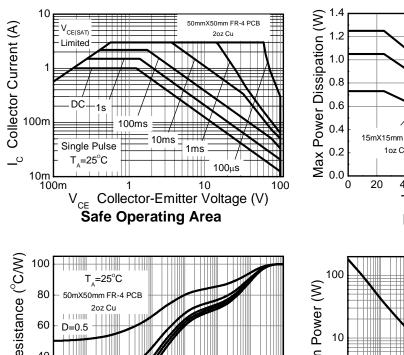
Characteristic	Symbol	Value	Unit		
	(Note 6)		0.73		
Collector Power Dissipation	(Note 7)	P _D	1.05	W	
Collector Fower Dissipation	(Note 8)		1.25	۷V	
	(Note 9)		1.81		
	(Note 6)		171		
Thermal Resistance, Junction to Ambient	(Note 7)	(Note 7)	119	°C/W	
iermai Resistance, Junction to Ambient	(Note 8)	$R_{ heta JA}$	100	C/VV	
	(Note 9)		69		
Thermal Resistance, Junction to Leads	(Note 10)	$R_{\theta JL}$	75.25	°C/W	
Operating and Storage Temperature Range		$T_{J_{i}}T_{STG}$	-55 to +150	°C	

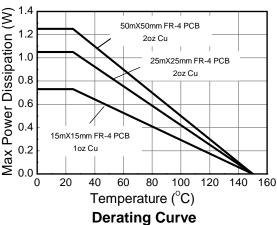
Notes:

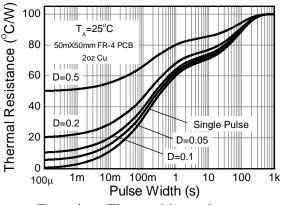
- 6. For the device mounted on 15mm X 15mm X 1.6mm FR-4 PCB with high coverage of single sided 1oz copper in still air condition.
 7. Mounted on 25mm X 25mm X 1.6mm FR-4 PCB with high coverage of single sided 2oz copper in still air condition.
 8. Mounted on 25mm X 25mm X 1.6mm FR-4 PCB with high coverage of single sided 2oz copper in still air condition.
- 9. As Note 7 above, measured at t < 5 secs.
- 10. Thermal resistance from junction to solder-point (at the end of the collector lead).

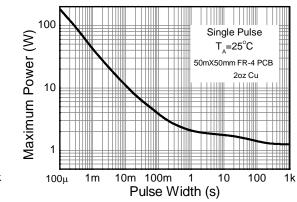


Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)









Transient Thermal Impedance

Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

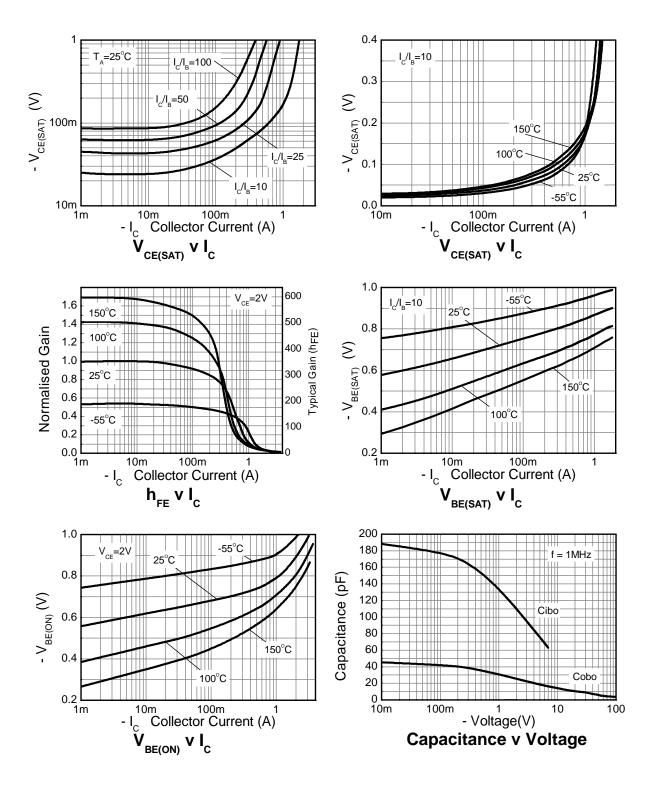
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-115	-180	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	-100	-140	-	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.4	-	V	$I_E = -100 \mu A$
Emitter-Base Breakdown Voltage	BV_{ECX}	-7	-8.3	-	V	I_E = -100μA, R_{BC} < 1k Ω or -0.25 < V_{BC} < 0.25V
Emitter-Base Breakdown Voltage	BV _{ECO}	-7	-8.8	-	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I	-	< -1	-50	nA	V _{CB} = -115V
Collector-Base Cuton Current	Ісво	-	-	-0.5	μΑ	V _{CB} = -115V, T _A = +100°C
Collector-Emitter Cutoff Current	I _{CEX}	-	-	-100	nA	$V_{CE} = -90V, R_{BE} < 1k\Omega \text{ or} $ $-0.25V < V_{BE} < 1V$
Emitter-Base Cutoff Current	I _{EBO}	-	< -1	-50	nA	V _{EB} = -5.6V
	h _{FE}	200	350	500		$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Ratio (Note 11)		180	320	-	-	$I_C = -100 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Ratio (Note 11)		110	190	-		$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
		20	35	-		$I_C = -1A$, $V_{CE} = -2V$
		-	-140	-210	mV	$I_C = -100 \text{mA}, I_B = -1 \text{mA}$
Collector-Emitter Saturation Voltage (Note 11)	V	-	-80	-110		$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Collector-Entitler Saturation Voltage (Note 11)	$V_{CE(SAT)}$	-	-180	-310	IIIV	$I_C = -500 \text{mA}, I_B = -20 \text{mA}$
		-	-150	-220		$I_C = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(SAT)}	-	-849	-950	mV	$I_C = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(ON)}$	-	-790	-900	mV	$I_C = -1A$, $V_{CE} = -2V$
Output Capacitance	C_obo	-	14.1	20	pF	$V_{CB} = -10V$, $f = 1MHz$
Transition Frequency	f _T	-	180	-	MHz	$V_{CE} = -15V, I_{C} = -20mA,$ f = 100MHz
Delay Time	t _D	-	15.8	-	ns	
Rise Time	t _R	-	41	-	ns	$V_{CC} = -10V, I_{C} = -500mA,$
Storage Time	ts	-	411	-	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Fall Time	t _F	-	89	-	ns	

Note:

11. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

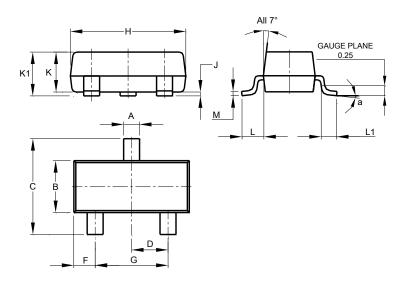




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

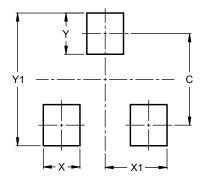


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	M 0.085		0.110				
а	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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